

Technical Data Sheet

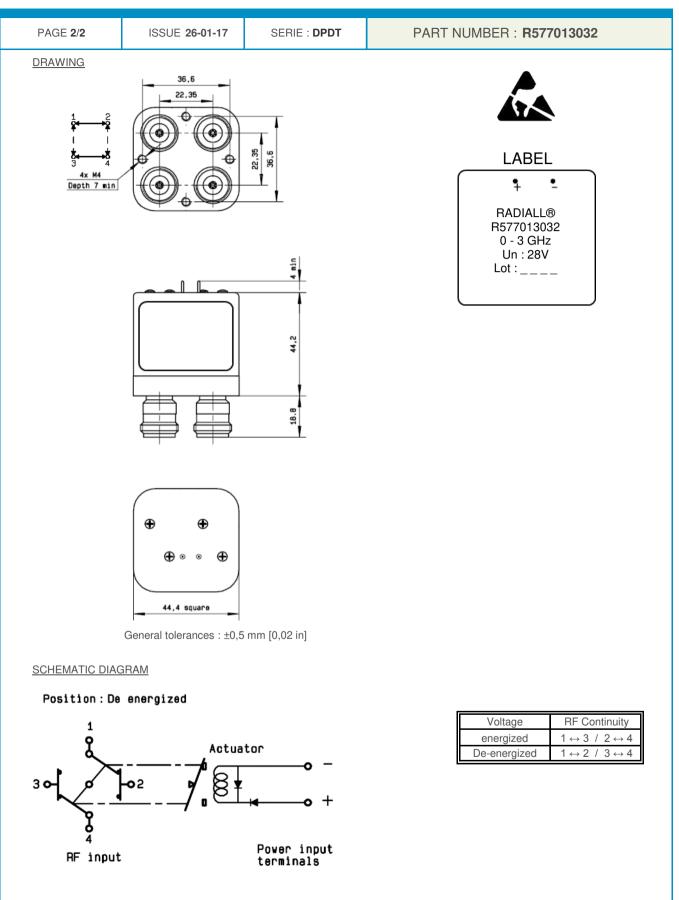
DPDT Ramses N 3GHz Failsafe 28Vdc Diodes Pins Terminals

	Frequency range				0 - 3 GHz				
	Impedance			:	50 Ohms	_			
	Frequency (GHz) VSWR max Insertion loss max Isolation min		DC - 1 1.15 0.15 dB 85 dB	1 - 2 1.20 0.20 dB 80 dB	2 - 3 1.25 0.25 dB 75 dB				
	Average pov	ver (*)	700 W	500 W	400 W				
	CTRICAL CHA	NAUTERIS	1105						
	Actuator Nominal cur	ront **			FAILSAFE				
Actuator voltage (Vcc)					28V (24 to 3	0V)			
	Terminals			:	solder pins	(250°C max. / 30 s	ec.)		
MEC	HANICAL CH	ARACTERIS	TICS						
	Connectors					er MIL-C 39012			
	Life Switching Ti	~~***			2.5 million o < 15 ms	cycles			
	Construction				Splashproo	f			
	Weight				< 215 g				
<u>ENV</u>	IRONMENTAI		ERISTICS						
	Operating te	mperature ra	inge	:	-40°C to +8	5°C			
	Storage tem	perature ran	ge	:	-55°C to +8	5°C	F	LOHS	
(*	Average pov	ver at 25°C r	er RF Path)				(•(().)
(**	At 25° C ±10)%))				CO	PLIAN	/
(***	Nominal volt	age ; 25° C)					<u>_</u>	PLIF	



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